



Vincotech

30-P2126PA075SC-L288F09Y

datasheet

flowPACK 2

1200 V / 75 A

Features

- Trench Fieldstop IGBTs for low saturation losses
- Open emitter configuration
- Compact and low inductive design
- Integrated NTC

Target applications

- Elevator Drives
- Embedded Drives
- Industrial Drives

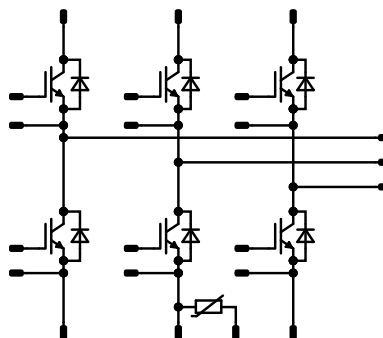
Types

- 30-P2126PA075SC-L288F09Y

flow 2 17 mm housing



Schematic





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Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	90	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	225	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	232	W
Gate-emitter voltage	V_{GES}		± 20	V
Short circuit ratings	t_{SC}	$V_{GE} = 15\text{ V}$, $V_{CC} = 800\text{ V}$ $T_j = 150\text{ °C}$	10	μs
Maximum junction temperature	T_{jmax}		175	$^{\circ}\text{C}$

Inverter Diode

Peak repetitive reverse voltage	V_{RRM}		1200	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	84	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	150	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	154	W
Maximum junction temperature	T_{jmax}		175	$^{\circ}\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^{\circ}\text{C}$
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	$^{\circ}\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2\text{ s}$	4000	V
Isolation voltage	V_{isol}	AC Voltage $t_p = 1\text{ min}$	2500	V
Creepage distance			min. 12,7	mm
Clearance			min. 12,7	mm
Comparative Tracking Index	CTI		≥ 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0026	25	5,3	5,8	6,3	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		75	25 125 150	1,58	1,83 2,12 2,19	2,07 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			1	µA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	r_g							10		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25		25		4300		pF
Reverse transfer capacitance	C_{res}							160		pF
Gate charge	Q_g		15		0	25		570		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,41		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 4 \Omega$ $R_{goff} = 4 \Omega$	± 15	600	75	25 125 150		149,4 160 164,4		ns
Rise time	t_r					25 125 150		38,8 44,2 43,2		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		250,2 311,8 328,6		ns
Fall time	t_f					25 125 150		75,97 121,53 135,61		ns
Turn-on energy (per pulse)	E_{on}					25 125 150		7,68 10,72 11,42		mWs
Turn-off energy (per pulse)	E_{off}					25 125 150		4,22 6,49 7,22		mWs



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]		Min	Typ	Max	

Inverter Diode

Static

Forward voltage	V_F				75	25 125 150	1,35	1,74 1,75 1,74	2,05 ⁽¹⁾	V
Reverse leakage current	I_R	$V_i = 1200$ V				25			14	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,62		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt=2324$ A/µs $di/dt=1749$ A/µs $di/dt=1360$ A/µs	± 15	600	75	25 125 150		40,35 49,16 51,85		A
Reverse recovery time	t_{rr}					25 125 150		351,15 496,84 546,36		ns
Recovered charge	Q_r					25 125 150		7,18 12,83 14,76		µC
Reverse recovered energy	E_{rec}					25 125 150		2,5 4,59 5,37		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		116,4 102,53 98,97		A/µs



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Thermistor

Static

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1486 \Omega$				100	-12		14	%
Power dissipation	P							200		mW
Power dissipation constant	d					25		2		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 3 \%$						3950		K
B-value	$B_{(25/100)}$	Tol. $\pm 3 \%$						3998		K
Vincotech Thermistor Reference									B	

⁽¹⁾ Value at chip level

⁽²⁾ Only valid with pre-applied Vincotech thermal interface material.



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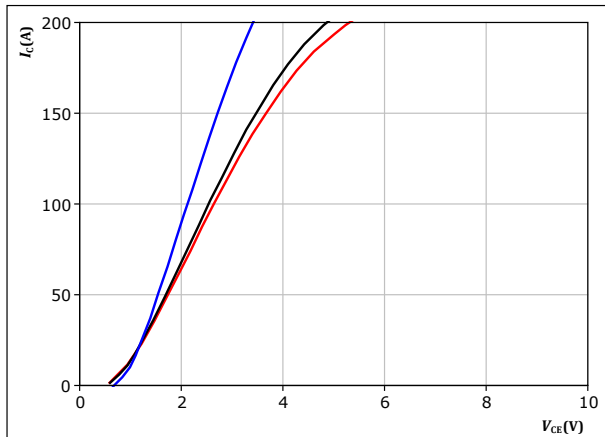
datasheet

Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

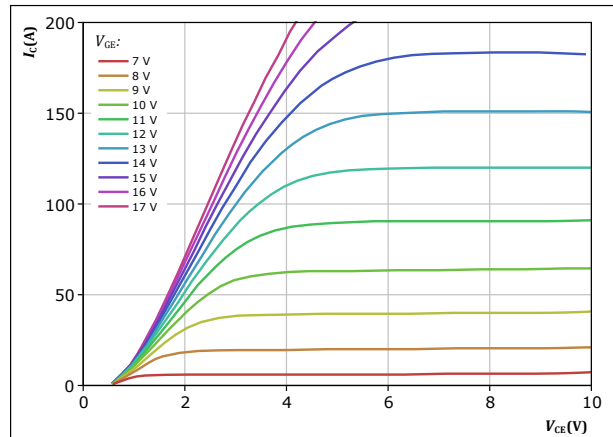


$t_p = 250 \mu s$
 $V_{GE} = 15 V$
 $T_j: 25 ^\circ C$
 $125 ^\circ C$
 $150 ^\circ C$

figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

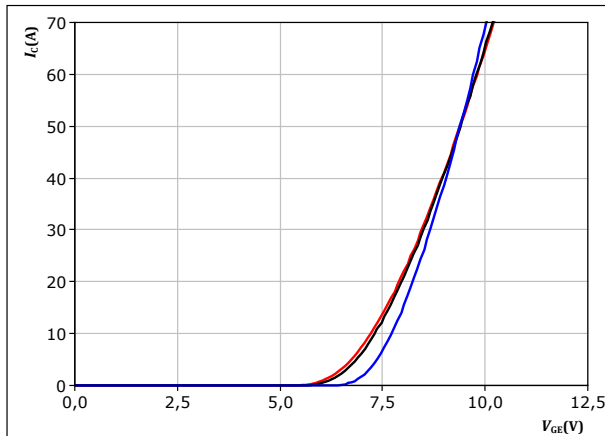


$t_p = 250 \mu s$
 $T_j = 150 ^\circ C$
 V_{GE} from 7 V to 17 V in steps of 1 V

figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

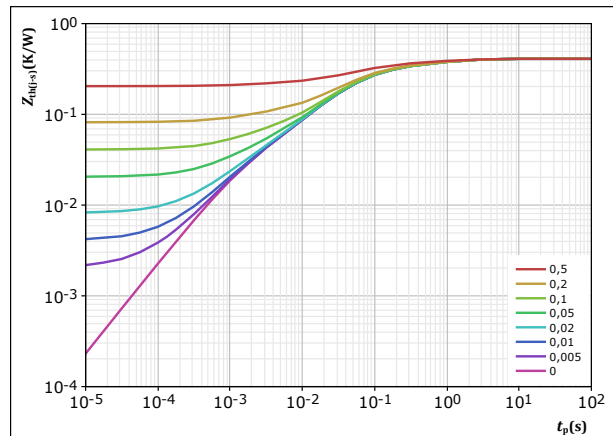


$t_p = 250 \mu s$
 $V_{CE} = 10 V$
 $T_j: 25 ^\circ C$
 $125 ^\circ C$
 $150 ^\circ C$

figure 4. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$
 $R_{th(j-s)} = 0,409 K/W$
IGBT thermal model values

$R (K/W)$	$\tau (s)$
6,08E-02	1,41E+00
9,91E-02	1,99E-01
1,78E-01	4,61E-02
5,03E-02	1,41E-02
2,16E-02	1,42E-03



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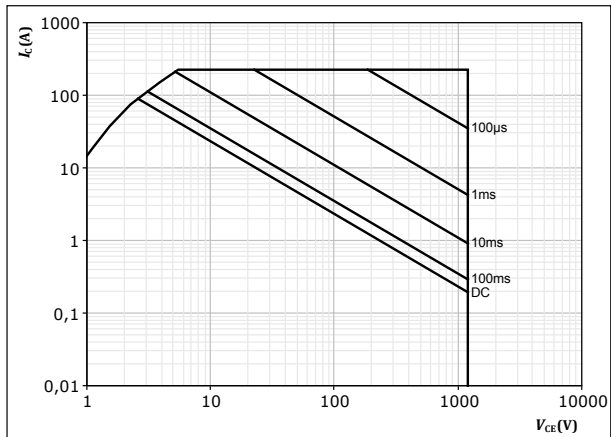
Inverter Switch Characteristics

figure 5.

IGBT

Safe operating area

$I_C = f(V_{CE})$



$D = \text{single pulse}$

$T_s = 80 \text{ } ^\circ\text{C}$

$V_{GE} = 15 \text{ V}$

$T_j = T_{jmax}$



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Inverter Diode Characteristics

figure 6.

FWD

Typical forward characteristics

$$I_F = f(V_F)$$

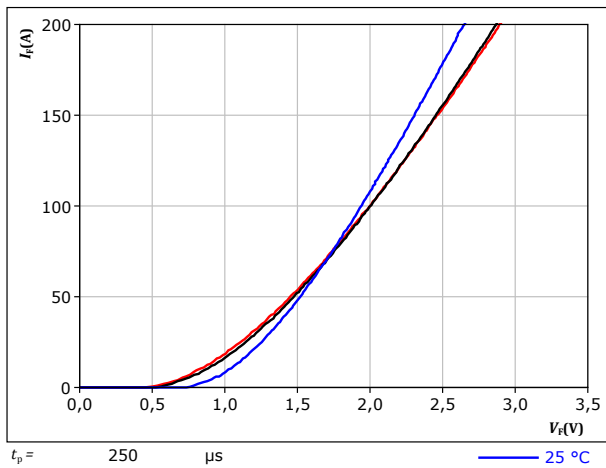
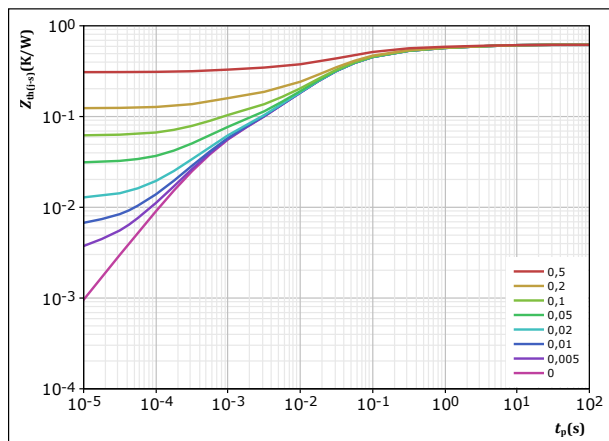


figure 7.

FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D =$	t_p / T
$R_{th(j-s)} =$	0,617 K/W
FWD thermal model values	
R (K/W)	τ (s)
4,35E-02	4,66E+00
7,48E-02	5,44E-01
1,95E-01	8,13E-02
2,13E-01	2,26E-02
4,51E-02	5,48E-03
4,51E-02	5,92E-04



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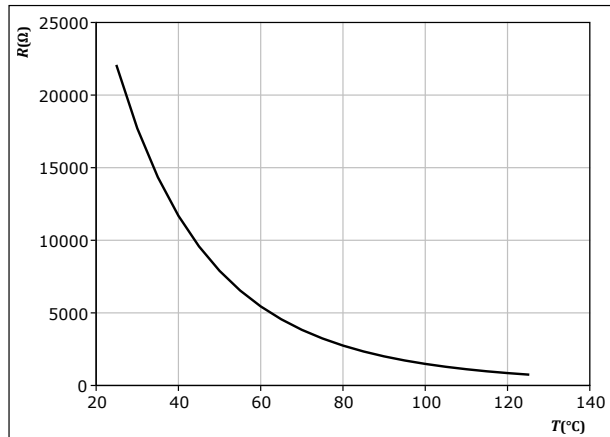
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datasheet

Thermistor Characteristics

figure 8. Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





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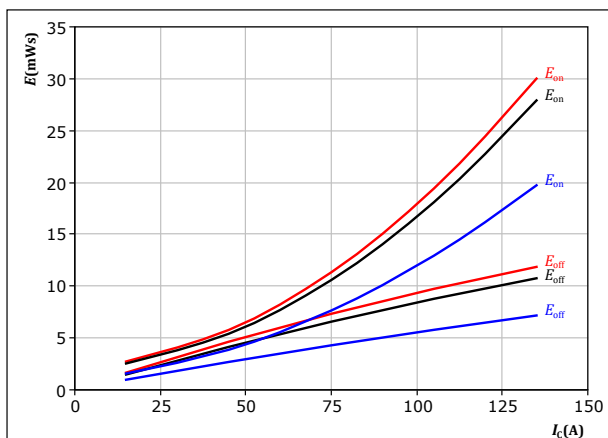
Inverter Switching Characteristics

figure 9.

IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 4$ Ω
 $R_{goff} = 4$ Ω

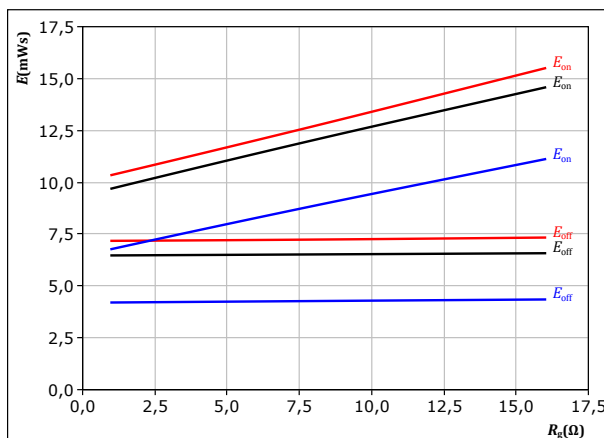
T_j : — 25 °C
— 125 °C
— 150 °C

figure 10.

IGBT

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 75$ A

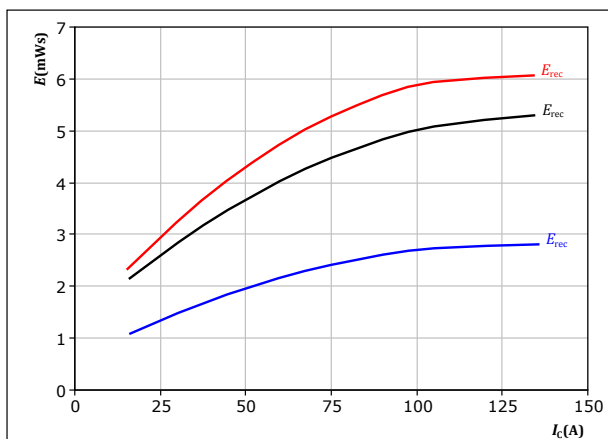
T_j : — 25 °C
— 125 °C
— 150 °C

figure 11.

FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 4$ Ω

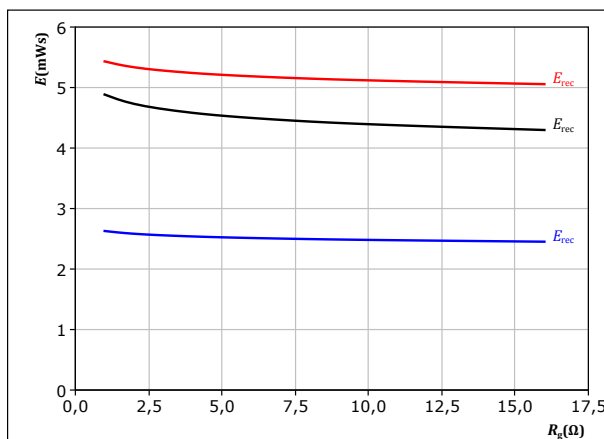
T_j : — 25 °C
— 125 °C
— 150 °C

figure 12.

FWD

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 75$ A

T_j : — 25 °C
— 125 °C
— 150 °C



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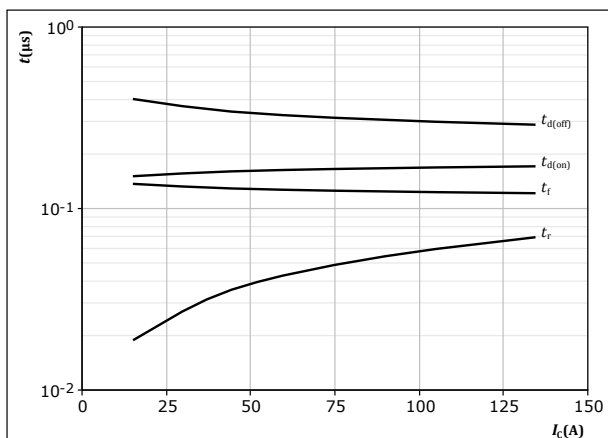
Inverter Switching Characteristics

figure 13.

IGBT

Typical switching times as a function of collector current

$$t = f(I_C)$$



With an inductive load at

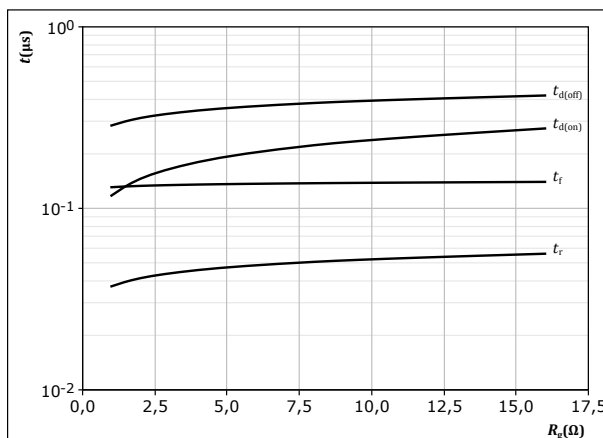
$T_j = 150$ °C
 $V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 4$ Ω
 $R_{goff} = 4$ Ω

figure 14.

IGBT

Typical switching times as a function of gate resistor

$$t = f(R_g)$$



With an inductive load at

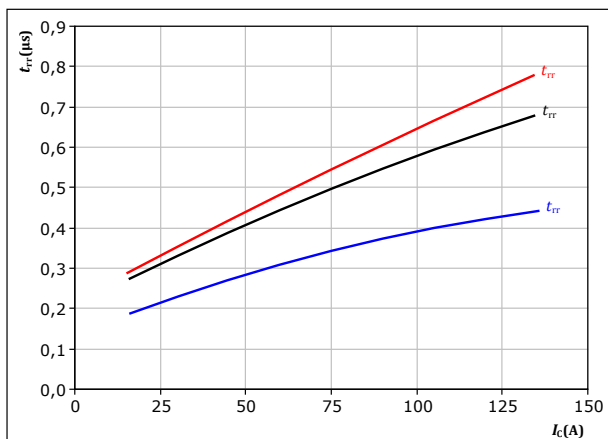
$T_j = 150$ °C
 $V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 75$ A

figure 15.

FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_C)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 4$ Ω

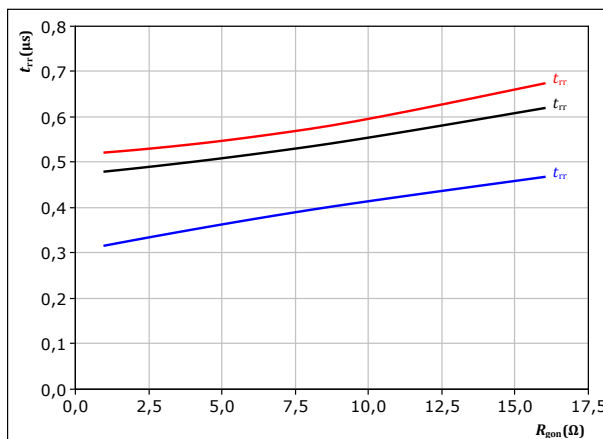
T_j : 25 °C
125 °C
150 °C

figure 16.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

$$t_{rr} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 75$ A

T_j : 25 °C
125 °C
150 °C



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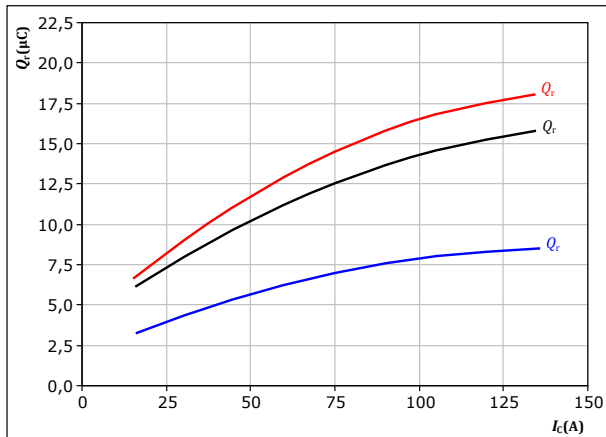
Inverter Switching Characteristics

figure 17.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 4$ Ω

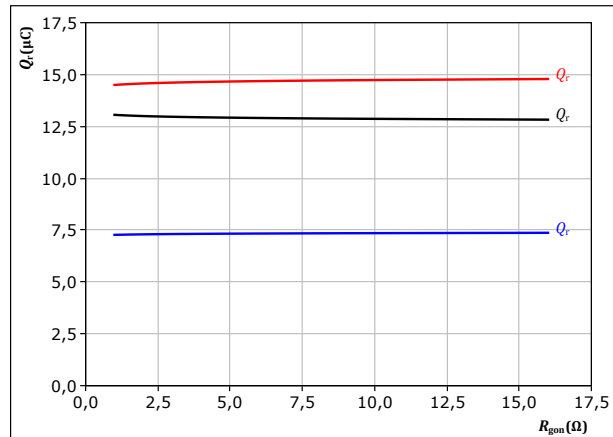
T_j :
— 25 °C
— 125 °C
— 150 °C

figure 18.

FWD

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 75$ A

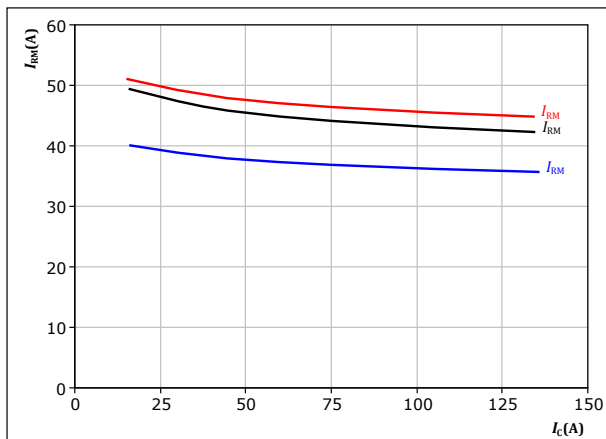
T_j :
— 25 °C
— 125 °C
— 150 °C

figure 19.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 4$ Ω

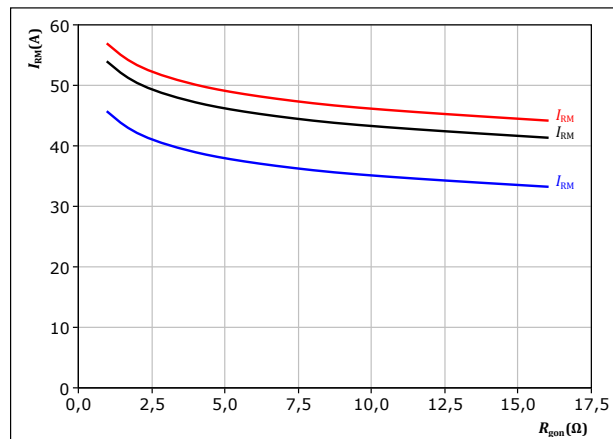
T_j :
— 25 °C
— 125 °C
— 150 °C

figure 20.

FWD

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 75$ A

T_j :
— 25 °C
— 125 °C
— 150 °C



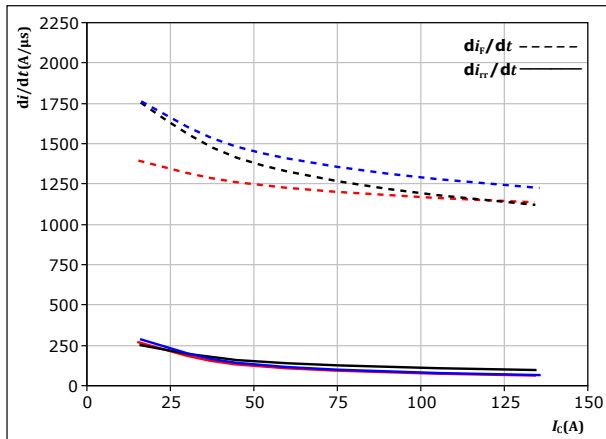
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Inverter Switching Characteristics

figure 21. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_r/dt = f(I_c)$



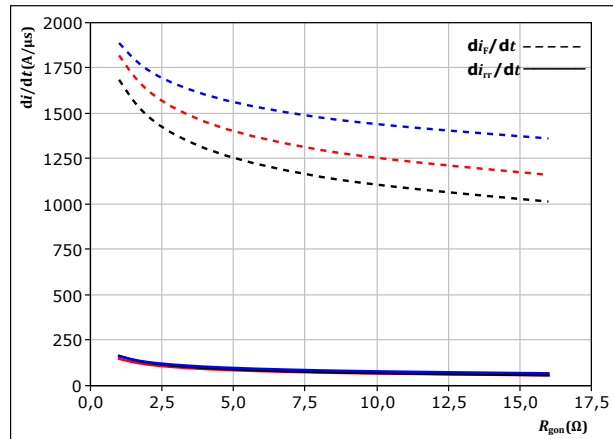
With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 4 \text{ } \Omega$

T_j :
— 25 °C
— 125 °C
— 150 °C

figure 22. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_r/dt = f(R_{gon})$



With an inductive load at

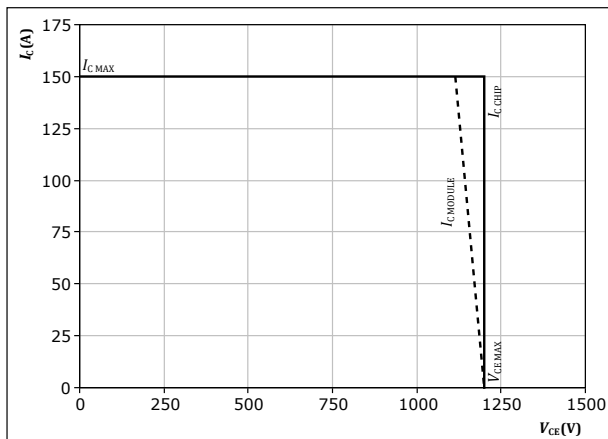
$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_c = 75 \text{ A}$

T_j :
— 25 °C
— 125 °C
— 150 °C

figure 23. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At $T_j = 150 \text{ } ^\circ\text{C}$
 $R_{gon} = 4 \text{ } \Omega$
 $R_{goff} = 4 \text{ } \Omega$



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Inverter Switching Definitions

figure 24. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

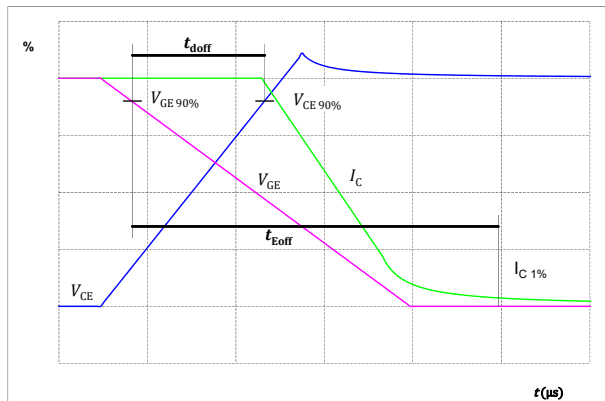


figure 25. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

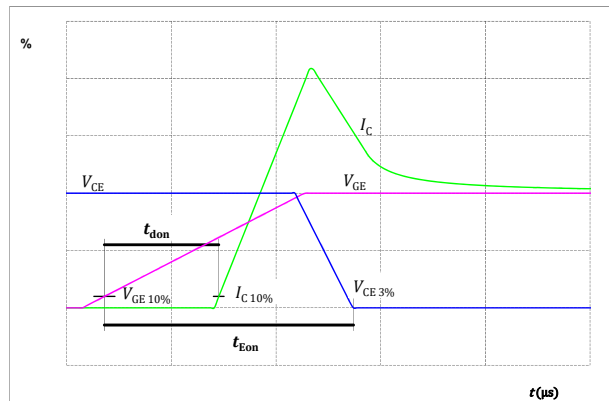


figure 26. IGBT

Turn-off Switching Waveforms & definition of t_f

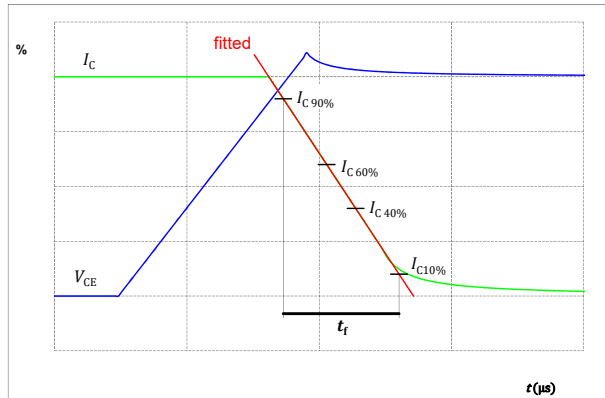
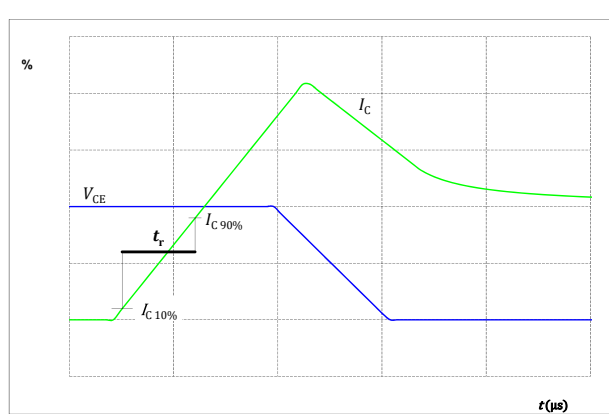


figure 27. IGBT

Turn-on Switching Waveforms & definition of t_r





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Inverter Switching Definitions

figure 28.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

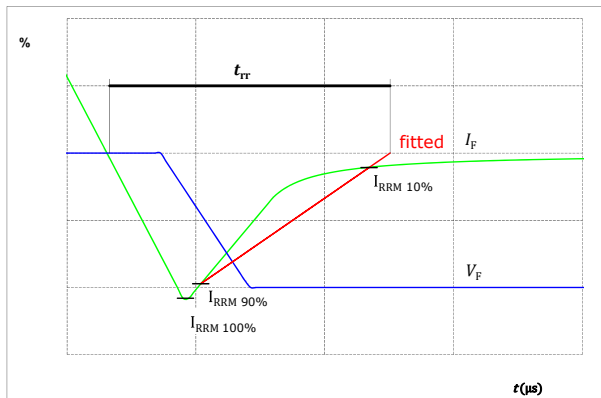
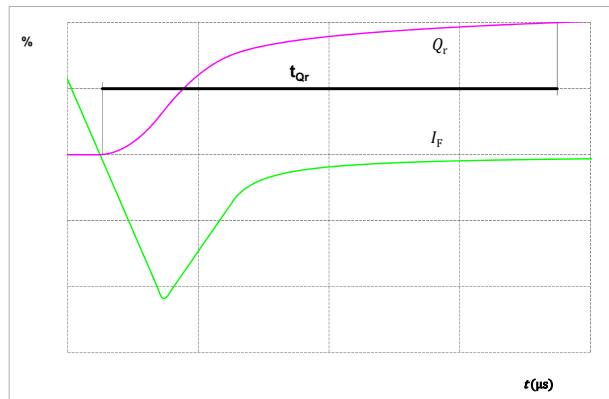


figure 29.

FWD

Turn-on Switching Waveforms & definition of t_{Qr} (t_{Qr} = integrating time for Q_r)





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30-P2126PA075SC-L288F09Y

datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	30-P2126PA075SC-L288F09Y
With thermal paste	30-P2126PA075SC-L288F09Y-/3/

Marking						
	Text	Name NN-NNNNNNNNNNNNNNNN- TTTTUVV	Date code WWYY	UL & VIN UL VIN	Lot LLLLL	Serial SSSS
	Datamatrix	Type&Ver TTTTTUVV	Lot number LLLLL	Serial SSSS	Date code WWYY	

Outline							
Pin table [mm]							
Pin	X	Y	Function	26	54,5	5,4	DC-3
1	0,9	0	S11	27	57,2	0	DC-3
2	0,9	3	G11	28	65,8	0	DC+3
3	3,9	0	DC-1	29	65,8	2,7	DC+3
4	3,9	2,7	DC-1	30	68,5	0	DC+3
5	3,9	5,4	DC-1	31	68,5	2,7	DC+3
6	6,6	0	DC-1	32	64,7	36	G16
7	15,2	0	DC+1	33	61,7	36	S16
8	15,2	2,7	DC+1	34	58,7	36	PH3
9	17,9	0	DC+1	35	56	36	PH3
10	17,9	2,7	DC+1	36	53,3	36	PH3
11	26,2	0	S13	37	50,6	36	PH3
12	26,2	3	G13	38	39,4	36	G14
13	29,2	0	DC-2	39	36,4	36	S14
14	29,2	2,7	DC-2	40	33,4	36	PH2
15	29,2	5,4	DC-2	41	30,7	36	PH2
16	31,9	0	DC-2	42	28	36	PH2
17	32,2	4,05	NTC	43	25,3	36	PH2
18	40,5	0	DC+2	44	14,1	36	G12
19	40,5	2,7	DC+2	45	11,1	36	S12
20	43,2	0	DC+2	46	8,1	36	PH1
21	43,2	2,7	DC+2	47	5,4	36	PH1
22	51,5	0	S15	48	2,7	36	PH1
23	51,5	3	G15	49	0	36	PH1
24	54,5	0	DC-3				
25	54,5	2,7	DC-3				

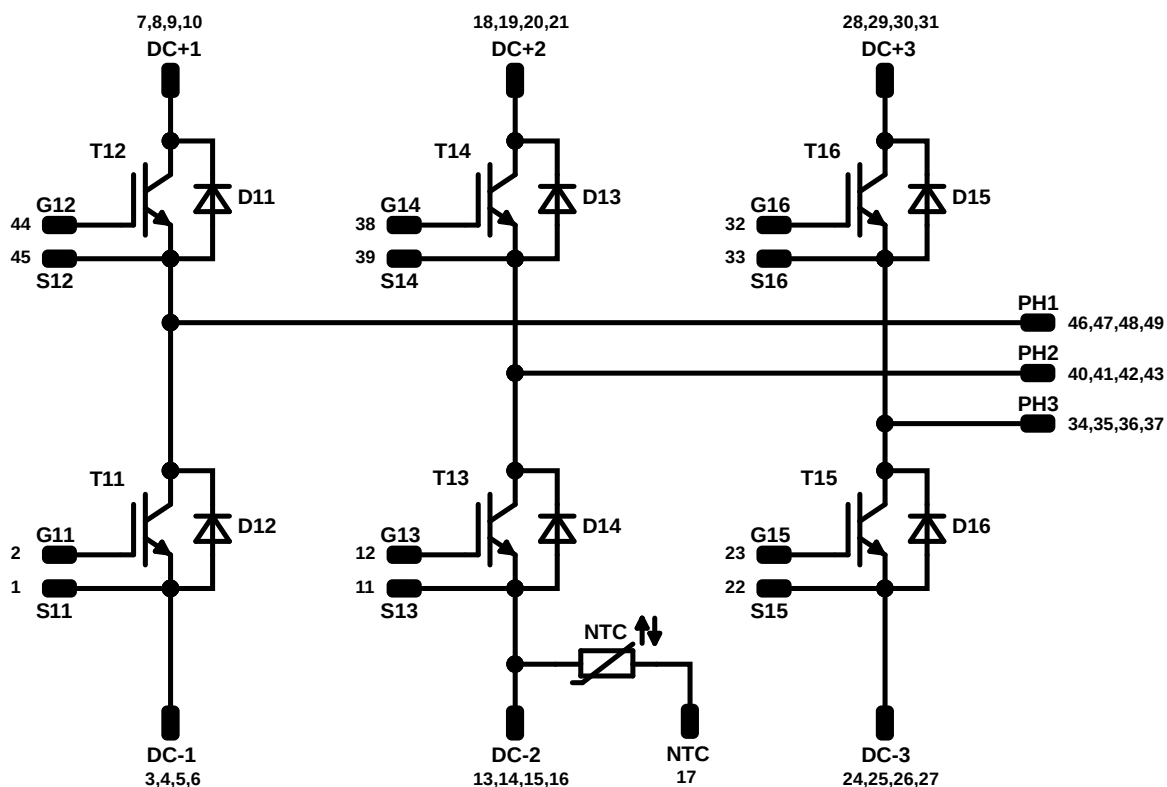


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30-P2126PA075SC-L288F09Y

datasheet

Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	75 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1200 V	75 A	Inverter Diode	
Rt	Thermistor			Thermistor	



Vincotech

30-P2126PA075SC-L288F09Y
datasheet

Packaging instruction				
Standard packaging quantity (SPQ) 36	>SPQ	Standard	<SPQ	Sample
Handling instruction				
Handling instructions for <i>flow 2</i> packages see vincotech.com website.				
Package data				
Package data for <i>flow 2</i> packages see vincotech.com website.				
Vincotech thermistor reference				
See Vincotech thermistor reference table at vincotech.com website.				
UL recognition and file number				
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.				

Document No.:	Date:	Modification:	Pages
30-P2126PA075SC-L288F09Y-D5-14	30 Sep. 2020	New Datasheet format	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.